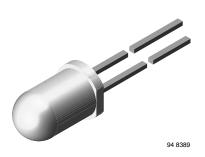


TSHA6200, TSHA6201, TSHA6202, TSHA6203

Vishay Semiconductors

GREEN

Infrared Emitting Diode, 875 nm, GaAlAs



DESCRIPTION

The TSHA620. series are infrared, 875 nm emitting diodes in GaAlAs technology, molded in a clear, untinted plastic package.

FEATURES

Package type: leadedPackage form: T-1¾

• Dimensions (in mm): Ø 5

• Peak wavelength: $\lambda_p = 875 \text{ nm}$

· High reliability

• Angle of half intensity: $\varphi = \pm 12^{\circ}$

Low forward voltage

Suitable for high pulse current operation

· Good spectral matching with Si photodetectors

 Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Note

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

- Infrared remote control and free air data transmission systems
- This emitter series is dedicated to systems with panes in transmission space between emitter and detector, because of the low absorbtion of 875 nm radiation in glass

PRODUCT SUMMARY					
COMPONENT	I _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)	
TSHA6200	40	± 12	875	600	
TSHA6201	50	± 12	875	600	
TSHA6202	60	± 12	875	600	
TSHA6203	65	± 12	875	600	

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TSHA6200	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		
TSHA6201	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		
TSHA6202	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		
TSHA6203	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾		

Note

· MOQ: minimum order quantity



www.vishay.com

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Reverse voltage		V _R	5	V		
Forward current		I _F	100	mA		
Peak forward current	$t_p/T = 0.5$, $t_p = 100 \mu s$	I _{FM}	200	mA		
Surge forward current	t _p = 100 μs	I _{FSM}	2.5	Α		
Power dissipation		P _V	180	mW		
Junction temperature		Tj	100	°C		
Operating temperature range		T _{amb}	- 40 to + 85	°C		
Storage temperature range		T _{stg}	- 40 to + 100	°C		
Soldering temperature	$t \le 5$ s, 2 mm from case	T _{sd}	260	°C		
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	230	K/W		

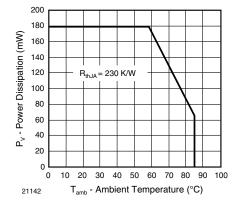


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

Fig. 2 - Forward Current Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP. MAX.		UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V _F		1.5	1.8	V
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}		- 1.6		mV/K
Reverse current	V _R = 5 V	I _R			100	μΑ
Junction capacitance	$V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$	C _j		20		pF
Temperature coefficient of φ _e	I _F = 20 mA	TKφ _e		- 0.7		%/K
Angle of half intensity		φ		± 12		deg
Peak wavelength	I _F = 100 mA	λρ		875		nm
Spectral bandwidth	I _F = 100 mA	Δλ		80		nm
Temperature coefficient of λ_p	I _F = 100 mA	TKλ _p		0.2		nm/K
Pira Pira	I _F = 100 mA	t _r		600		ns
Rise time	I _F = 1 A	t _r		300		ns
Fall time	I _F = 100 mA	t _f	600	ns		
r all tillie	I _F = 1 A	t _f		300	300	
Virtual source diameter		d		3.7		mm



www.vishay.com

Vishay Semiconductors

TYPE DEDICATED CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	L 1 A + 100 vs	TSHA6200	V _F		2.8	3.5	V
Forward valtage		TSHA6201	V_{F}		2.8	3.5	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	TSHA6202	V_{F}		2.8	3.5	V
		TSHA6203	V_{F}		2.8	3.5	V
	I _F = 100 mA, t _p = 20 ms -	TSHA6200	l _e	25	40	125	mW/sr
		TSHA6201	l _e	30	50	125	mW/sr
		TSHA6202	l _e	36	60	125	mW/sr
Dadient intensity		TSHA6203	l _e	50	65	125	mW/sr
Radiant intensity		TSHA6200	l _e	200	330		mW/sr
	I 1 4 4 100	TSHA6201	l _e	260	400		mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	TSHA6202	l _e	330	460		mW/sr
		TSHA6203	l _e	400	530		mW/sr
		TSHA6200	φ _e		22		mW
Redient newer	- 100 mA + - 20 ma	TSHA6201	фе		23		mW
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TSHA6202	фe		24		mW
		TSHA6203	фe		25		mW

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

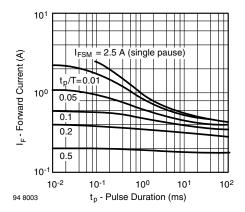


Fig. 3 - Pulse Forward Current vs. Pulse Duration

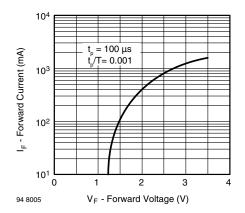


Fig. 4 - Forward Current vs. Forward Voltage

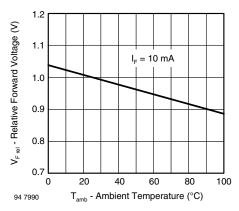


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

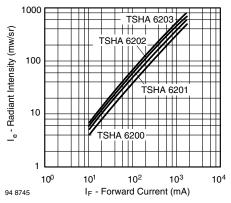


Fig. 6 - Radiant Intensity vs. Forward Current

Vishay Semiconductors

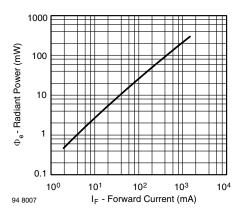


Fig. 7 - Radiant Power vs. Forward Current

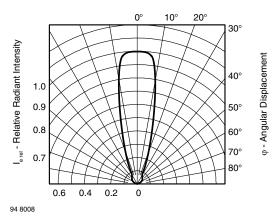


Fig. 10 - Relative Radiant Intensity vs. Angular Displacement

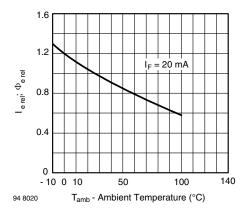


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature

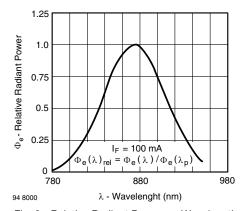


Fig. 9 - Relative Radiant Power vs. Wavelength

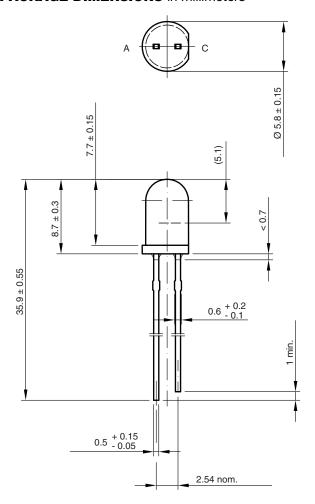
ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



www.vishay.com

Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters



Area not plane

Ø 5 ± 0.15

technical drawings according to DIN specifications

Drawing-No.: 6.544-5259.04-4

Issue: 8; 19.05.09

96 12125



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000